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MARKING DIAGRAMS

Low-Voltage Quad 2-Input NAND Gate with 5 V Tolerant Inputs

74LCX00

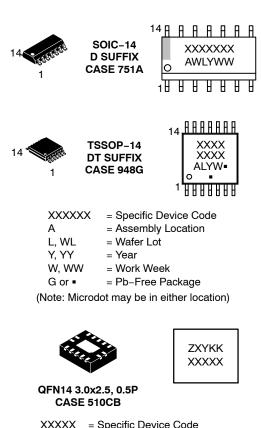
General Description

The LCX00 contains four 2–input NAND gates. The inputs tolerate voltages up to 5.5 V allowing the interface of 5 V systems to 3 V systems.

The 74LCX00 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5 V Tolerant Inputs
- $1.65 \text{ V} 5.5 \text{ V} \text{ V}_{CC}$ Specifications Provided
- 5.2 ns t_{PD} Max. (V_{CC} = 3.3 V), 10 μ A I_{CC} Max.
- Power Down High Impedance Inputs and Outputs
- ± 24 mA Output Drive (V_{CC} = 3.0 V)
- Implements Proprietary Noise/EMI Reduction Circuitry
- Latch-up Performance Exceeds JEDEC 78 Conditions
- ESD performance:
 - Human Body Model >2000 V
- Available on SOIC, TSSOP and Leadless QFN Packages
- These Devices are Pb-Free, Halide Free and are RoHS Compliant



XXXXX	= Specific Device Code
Z	= Assembly Plant Code
XY	= Date Code
KK	= Lot Run Traceability Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 8 of this data sheet.

CONNECTION DIAGRAMS

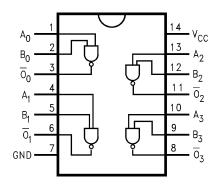


Figure 1. Pin Assignments for SOIC and TSSOP

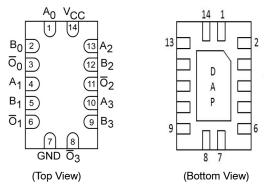


Figure 2. Pad Assignments for DQFN

LOGIC SYMBOL

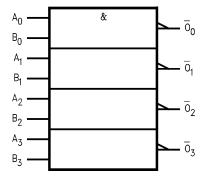


Figure 3. IEEE/IEC

PIN DESCRIPTION

Pin Names	Description
A _n , B _n	Inputs
Ōn	Outputs
DAP	No Connect

NOTE: DAP (Die Attach Pad)





ABSOLUTE MAXIMUM RATINGS

Symbol	Paramete	r	Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to +6.5	V
VI	DC Input Voltage (Note 1)		-0.5 to +6.5	V
V _O	DC Output Voltage (Note 1)	Active-Mode (High or Low State) Tri-State Mode Power-Down Mode (V _{CC} = 0 V)	-0.5 to V _{CC} + 0.5 -0.5 to +6.5 -0.5 to +6.5	V
Ι _{ΙΚ}	DC Input Diode Current	V _I < GND	-50	mA
I _{OK}	DC Output Diode Current	V _O < GND	-50	mA
Ι _Ο	DC Output Source/Sink Current		±50	mA
I_{CC} or I_{GND}	DC Supply Current per Supply Pin or Ground	Pin	±100	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 se	ecs	260	°C
ТJ	Junction Temperature Under Bias		+150	°C
θ_{JA}	Thermal Resistance (Note 1)	SOIC-14 QFN14 TSSOP-14	116 130 150	°C/W
P _D	Power Dissipation in Still Air at 125°C	SOIC-14 QFN14 TSSOP-14	1077 962 833	mW
MSL	Moisture Sensitivity		Level 1	-
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	-
V_{ESD}	ESD Withstand Voltage (Note 3)	Human Body Model Charged Device Model	2000 N/A	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

I_O absolute maximum rating must be observed. 1.

 Measured with minimum pad spacing on an FR4 board, using 76 mm-by-114 mm, 2-ounce copper trace no air flow per JESD51-7.
HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.

RECOMMENDED OPERATING CONDITIONS

Symbol	F	Parameter			Max	Unit
V _{CC}	Supply Voltage	Operating Data Retention Only	1.65 1.5	3.3 3.3	5.5 5.5	V
VI	Digital Input Voltage		0	-	5.5	V
Vo	Output Voltage	Active Mode (High or Low State) Tri–State Mode Power Down Mode (V _{CC} = 0 V)	0 0 0	- -	V _{CC} 5.5 5.5	V
T _A	Operating Free-Air Temperature		-40	-	+125	°C
t _r , t _f	Input Rise or Fall Rate	$\label{eq:VCC} \begin{array}{l} V_{CC} = 1.65 \; V \; to \; 1.95 \; V \\ V_{CC} = 2.3 \; V \; to \; 2.7 \; V \\ V_{IN} \; from \; 0.8 \; V \; to \; 2.0 \; V, \; V_{CC} = 3.0 \; V \\ V_{CC} = 4.5 \; V \; to \; 5.5 \; V \end{array}$	0 0 0 0	- - - -	20 20 10 5	nS/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

4. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.



DC ELECTRICAL CHARACTERISTICS

				T _A = -40°0	to +85°C T _A = -4		A = −40°C to +125°C	
Symbol	Parameter	Conditions	V _{CC} (V)	Min	Max	Min	Max	Unit
VIH	HIGH Level Input Voltage		1.65 – 1.95	$0.65 \times V_{CC}$	-	$0.65 \times V_{CC}$	-	V
			2.3 – 2.7	1.7	-	1.7	-	
			3.0 - 3.6	2.0	-	2.0	-	
			4.5 – 5.5	$0.70 \times V_{CC}$	-	$0.70 \times V_{CC}$	-	
V_{IL}	LOW Level Input Voltage		1.65 – 1.95	-	$0.35 \times V_{CC}$	-	$0.35 \times V_{CC}$	V
			2.3 – 2.7	-	0.7	-	0.7	
			3.0 - 3.6	-	0.8	-	0.8	
			4.5 – 5.5	-	$0.30 \times V_{CC}$	-	$0.30 \times V_{CC}$	
V _{OH}	High-Level Output Voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$						V
		I _{OH} = −100 μA	1.65 – 5.5	V _{CC} – 0.1	-	V _{CC} – 0.1	-	
		I _{OH} = -4 mA	1.65	1.29	-	1.29	-	
		I _{OH} = -8 mA	2.3	1.8	-	1.8	-	
		I _{OH} = -12 mA	2.7	2.2	-	2.2	-	
		I _{OH} = -16 mA	3.0	2.4	-	2.4	-	
		I _{OH} = -24 mA	3.0	2.2	-	2.2	-	
		I _{OH} = -32 mA	4.5	3.7		3.7	-	
V _{OL}	Low-Level Output Voltage	$V_I = V_{IH} \text{ or } V_{IL}$						V
		I _{OL} = 100 μA	1.65 – 5.5	-	0.1	-	0.1	
		$I_{OL} = 4 \text{ mA}$	1.65	-	0.24	-	0.24	
		I _{OL} = 8 mA	2.3	-	0.3	-	0.3	
		I _{OL} = 12 mA	2.7	-	0.4	-	0.4	
		I _{OL} = 16 mA	3.0	-	0.4	-	0.4	
		I _{OL} = 24 mA	3.0	-	0.55	-	0.55	
		I _{OL} = 32 mA	4.5	-	0.6	-	0.6	
I	Input Leakage Current	V _I = 0 to 5.5 V	1.65 – 5.5	-	±5.0	-	±5.0	μA
I _{OFF}	Power Off Leakage Current	V _I = 5.5 V or	0	-	10	-	10	μA
		V _O = 5.5 V						
I _{CC}	Quiescent Supply Current	$V_{I} = 5.5 V \text{ or GND}$	1.65 – 5.5	-	10	-	10	μA
ΔI_{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6 V$	2.3 – 3.6	_	500	-	500	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



AC ELECTRICAL CHARACTERISTICS

				$T_A = -40^{\circ}C$	C to +85°C	$T_A = -40^{\circ}C$	to +125°C							
Symbol	Parameter	Test Condition	V _{CC} (V)	Min	Max	Min	Max	Unit						
t _{PLH} , t _{PHL}	Propagation Delay, Input to	See Figures 4	1.65 –1.95	-	10	-	10	ns						
	Output and 5	and 5	2.3 – 2.7	_	6.2	-	6.6							
			2.7	_	6.0	-	6.2							
									3.0 –	3.0 – 3.6	_	5.2	-	5.5
			4.5 – 5.5	_	4.2	-	5.6							
t _{OSHL} , t _{OSLH}	Output to Output Skew		1.65 – 1.95	_	-	-	-	ns						
			2.3 – 2.7	_	-	-	-							
						2.7	_	-	-	-				
			3.0 – 3.6	_	1.0	-	1.0							
			4.5 – 5.5	-	_	-	-							

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

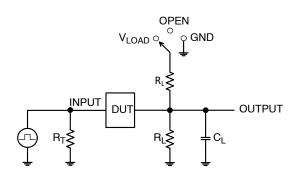
DYNAMIC SWITCHING CHARACTERISTICS

				T _A = 25°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Typical	Unit
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	3.3	C_{L} = 50 pF, V_{IH} = 3.3 V, V_{IL} = 0 V	0.8	V
		2.5	C_{L} = 30 pF, V_{IH} = 2.5 V, V_{IL} = 0 V	0.6	
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	3.3	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	-0.8	V
		2.5	$C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$	-0.6	

CAPACITANCE

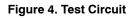
Symbol	Parameter	Conditions	Typical	Unit
C _{IN}	Input Capacitance	V_{CC} = Open, V_I = 0 V or V_{CC}	7	pF
C _{OUT}	Output Capacitance	V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC},f = 10 MHz	25	pF

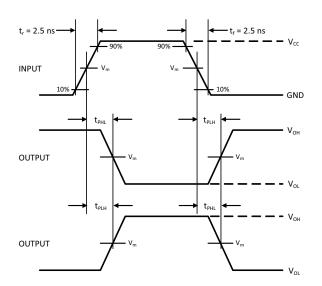


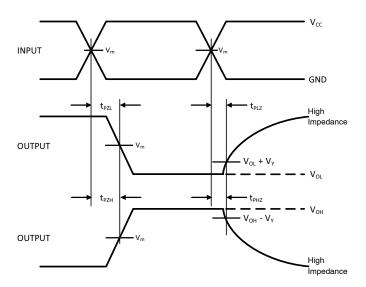


Test	Switch Position
t _{PLH} / t _{PHL}	Open
t _{PLZ} / t _{PZL}	V _{LOAD}
t _{PHZ} / t _{PZH}	GND

 C_L includes probe and jig capacitance R_T is Z_{OUT} of pulse generator (typically 50 Ω) f = 1 Mhz, t_W = 500 ns







V _{CC} , V	R_{L}, Ω	C _L , pF	V _{LOAD}	V _m , V	V _Y , V
1.65 to 1.95	500	30	$2 \times V_{CC}$	V _{CC} /2	0.15
2.3 to 2.7	500	30	$2 \times V_{CC}$	V _{CC} /2	0.15
2.7	500	50	6 V	1.5	0.3
3.0 to 3.6	500	50	6 V	1.5	0.3
4.5 to 5.5	500	50	$2 \times V_{CC}$	V _{CC} /2	0.3

Figure 5. Switching Waveforms



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SCHEMATIC DIAGRAM (Generic for LCX Family)

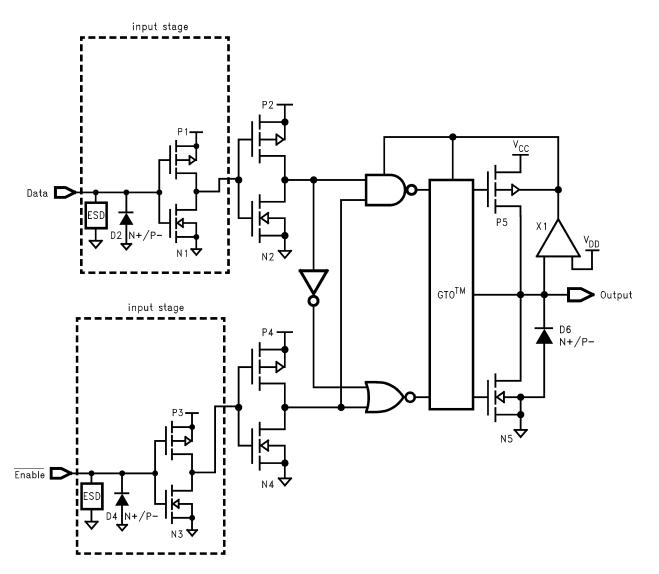


Figure 6. Schematic Diagram (Generic for LCX Family)



ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
74LCX00MTCX	LCX 00	TSSOP-14	2500 / Tape & Reel
74LCX00BQX	LCX00	QFN-14	3000 / Tape & Reel

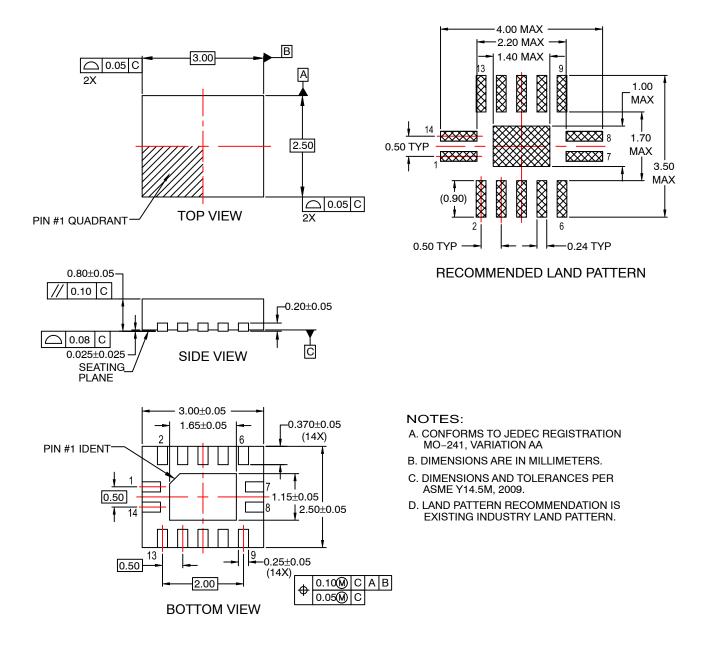
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





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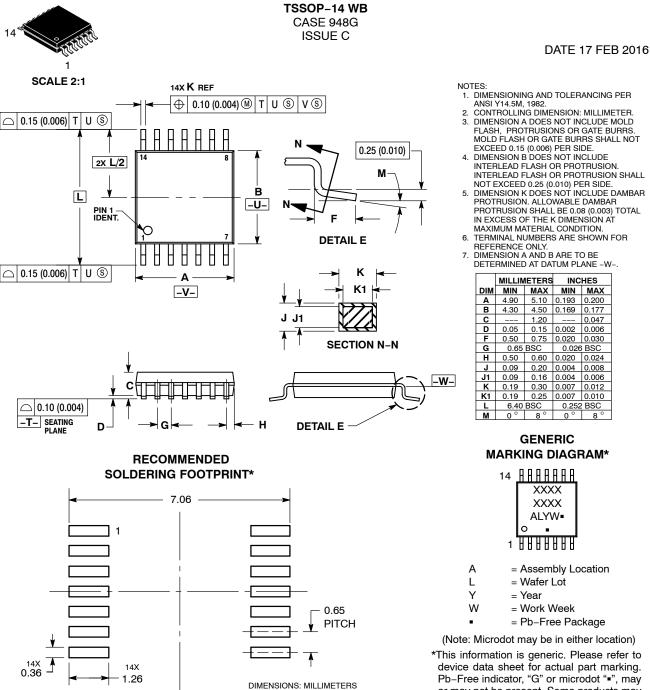
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SOIC14 CASE 751EF **ISSUE O** DATE 30 SEP 2016 8.75 Α 8.50 0.65 7.62 14 8 14 8 В ₽ ╞ 4.00 6.00 5.60 3.80 Ħ = ╞ = Ħ 1.70 7 **PIN #1** 7 1.27 1 0.51 IDENT. 1.270.35 (0.33) - \oplus 0.25 (M) С В Α LAND PATTERN RECOMMENDATION TOP VIEW 1.75 MAX 0.25 0.19 0.10 С 1.50 0.25 1.25 0.10 SIDE VIEW FRONT VIEW NOTES: A. CONFORMS TO JEDEC MS-012, VARIATION AB, ISSUE C **B. ALL DIMENSIONS ARE IN MILLIMETERS** 0.50 0.25 × 45° C. DIMENSIONS DO NOT INCLUDE MOLD FLASH OR BURRS R0.10 GAGE D. LAND PATTERN STANDARD: PLANE SOIC127P600X145-14M E. CONFORMS TO ASME Y14.5M, 2009 R0.10 0.36 8° 0° 0.90 0.50 SEATING PLANE (1.04)**DETAIL A** SCALE 16:1

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